

Features

- Split Gate Trench MOSFET Technology
- · Low Thermal Resistance
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

• Operating Junction Temperature Range: -55°C to +150°C

• Storage Temperature Range: -55°C to +150°C

• Thermal Resistance: 40°C/W Junction to Ambient(Note2)

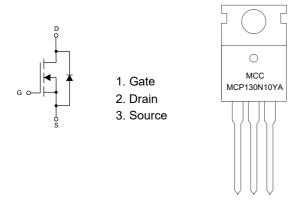
• Thermal Resistance: 0.5°C/W Junction to Case

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V _{DS}	100	V
Gate-Source Volltage		V _{GS}	±20	V
Continuous Drain Current	T _C =25°C	. I _D	130	Α
	T _C =100°C		82	
Pulsed Drain Current ^(Note 3)		I _{DM}	520	Α
Total Power Dissipation(Note 4)		P _D	250	W
Single Pulsed Avalanche Energy ^(Note 5)		E _{AS}	552	mJ

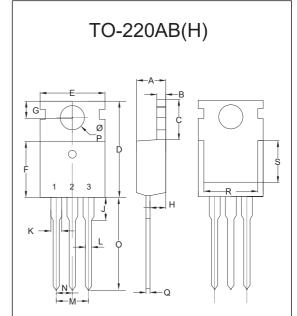
Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\theta JA}$ is measured with the device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_D is based on max. junction temperature, using junction-case thermal resistance.
- 5. T_J =25°C, V_{DD} =50V, V_{GS} =10V, R_G =25 Ω , L=2mH.

Internal Structure and Marking Code



N-Channel MOSFET



DIMENSIONS					
DIM INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.172	0.188	4.37	4.77	
В	0.049	0.057	1.25	1.45	
С	0.246	0.270	6.25	6.85	
D	0.594	0.634	15.10	16.10	
E	0.382	0.406	9.70	10.30	
F	0.346	0.370	8.80	9.40	
G	0.102	0.118	2.60	3.00	
Н	0.087	0.102	2.20	2.60	
J		0.134		3.40	
K	0.046	0.058	1.17	1.47	
L	0.028	0.037	0.70	0.95	
М	0.200		5.08		TYP.
N	0.100		2.54		TYP.
0	0.502	0.543	12.75	13.80	
Р	0.134	0.150	3.40	3.80	Ф
Q	0.016	0.026	0.40	0.65	
R	0.276		7.00		
S	0.217		5.50		

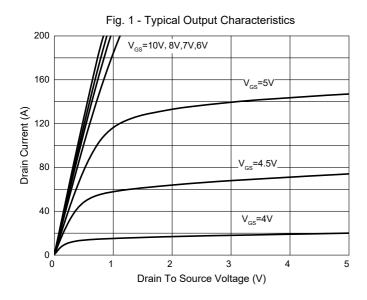


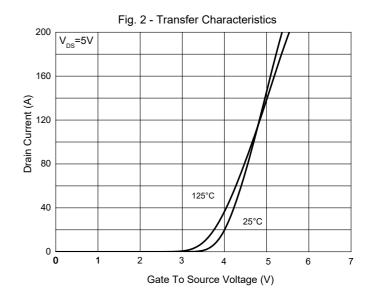
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

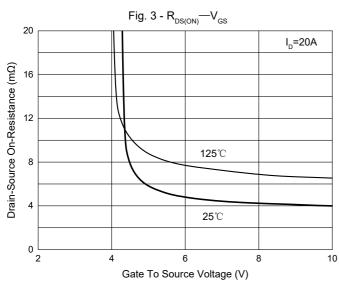
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics	-		<u> </u>	1	1		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	100			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V, V _{GS} =0V			1	μA	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2	2.8	4	V	
Drain-Source On-Resistance		V _{GS} =10V, I _D =20A		4.1	5.5	0	
	R _{DS(on)}	V _{GS} =10V, I _D =65A		4.2	5.5	mΩ	
Gate Resistance	R_G	f=1MHz, Open drain		0.8		Ω	
Diode Characteristics							
Continuous Body Diode Current	Is				130	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =20A			1.3	V	
Reverse Recovery Time	t _{rr}			63		ns	
Reverse Recovery Charge	Q _{rr}	l _F =20A, dl _F /dt=100A/μs		77		nC	
Dynamic Characteristics			'				
Input Capacitance	C _{iss}			4458			
Output Capacitance	C _{oss}	V _{DS} =50V,V _{GS} =0V,f=1MHz		1921		pF	
Reverse Transfer Capacitance	C _{rss}			20		•	
Total Gate Charge	Q_g			60			
Gate-Source Charge	Q_{gs}	V _{DS} =50V,V _{GS} =10V,I _D =55A		17		nC	
Gate-Drain Charge	Q_{gd}			10			
Turn-On Delay Time	t _{d(on)}			18.7			
Turn-On Rise Time	t _r	V _{DD} =50V, V _{GS} =10V,		10.6			
Turn-Off Delay Time	t _{d(off)}	$R_G=2.2\Omega$, $I_{DS}=55A$		33		ns	
Turn-Off Fall Time	t _f			11			

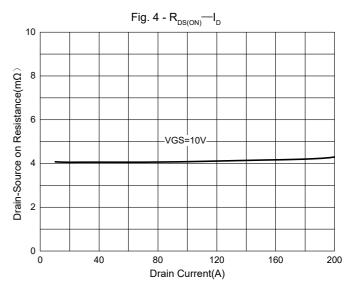


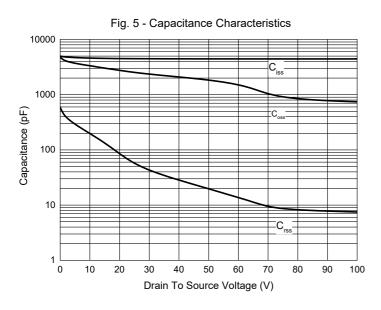
Curve Characteristics

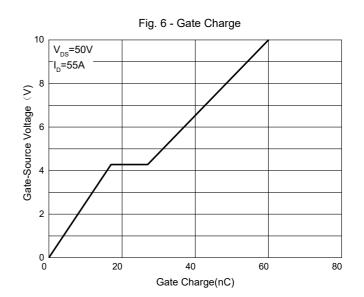






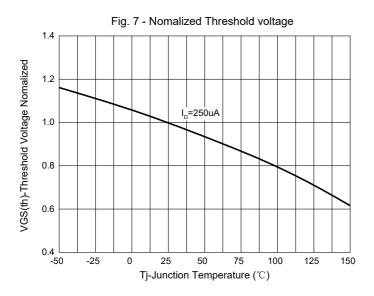


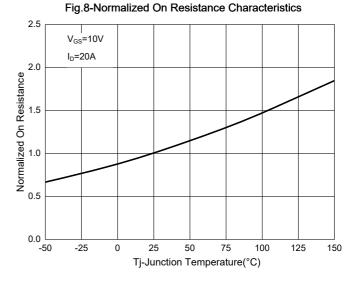


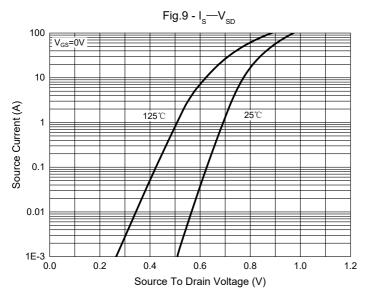


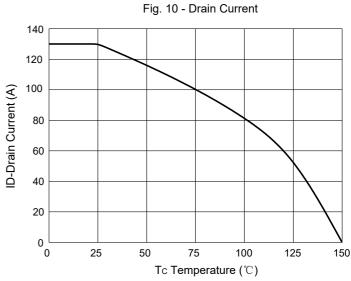


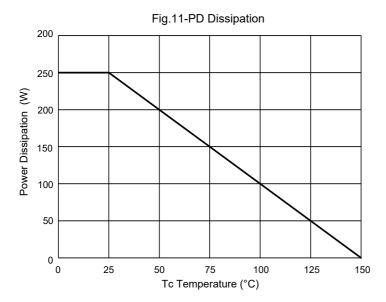
Curve Characteristics





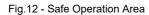








Curve Characteristics



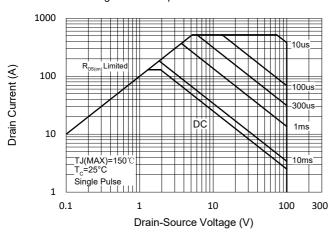
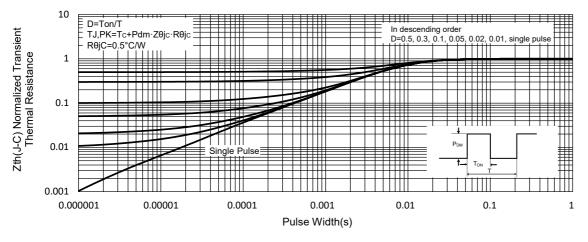


Fig.13 - Normalized Transient Thermal Impedance





Ordering Information

Device	Packing
Part Number-BP	Bulk:50pcs/Tube,1Kpcs/Box,5Kpcs/Carton

IMPORTANT NOTICE

Micro Commercial Components Corp. reserves the right to make changes without further notice to any product herein to make corrections, modifications, enhancements, improvements, or other changes. **Micro Commercial Components Corp.** does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold **Micro Commercial Components Corp.** and all the companies whose products are represented on our website, harmless against all damages. **Micro Commercial Components Corp.** products are sold subject to the general terms and conditions of commercial sale, as published at

https://www.mccsemi.com/Home/TermsAndConditions.

LIFE SUPPORT

MCC's products are not authorized for use as critical components in life support devices or systems without the express written approval of Micro Commercial Components Corporation.

CUSTOMER AWARENESS

Counterfeiting of semiconductor parts is a growing problem in the industry. Micro Commercial Components (MCC) is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. MCC strongly encourages customers to purchase MCC parts either directly from MCC or from Authorized MCC Distributors who are listed by country on our web page cited below. Products customers buy either from MCC directly or from Authorized MCC Distributors are genuine parts, have full traceability, meet MCC's quality standards for handling and storage. MCC will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. MCC is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.